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Silicon Epitaxial Planar Zener Diodes for Voltage Controller & Voltage Limitter



ADE-208-123E (Z)

Rev.5 Mar. 2002

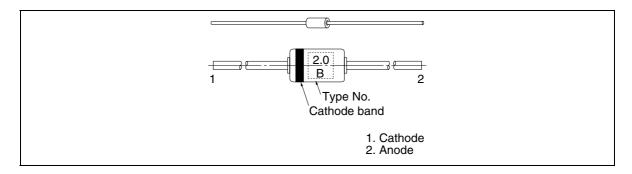
Features

- Wide spectrum from 1.88 V through 40 V of zener voltage provide flexible application.
- Glass package DO-41 structure ensures high reliability.

Ordering Information

Type No.	Mark	Package Code		
HZ-P Series	Type No.	DO-41		

Pin Arrangement



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Value	Unit	
Power dissipation	Pd	1.0	W	•
Junction temperature	Tj	175	°C	
Storage temperature	Tstg	-55 to +175	°C	-

Electrical Characteristics

 $(Ta = 25^{\circ}C)$

Type Grade V_z (V)*** Test Condition of Ln (μA) Image In (μA) <th></th> <th></th> <th colspan="2">Zener Voltage</th> <th></th> <th colspan="2">Reverse Curre</th> <th colspan="2">rent Dynamic Resistance</th>			Zener Voltage			Reverse Curre		rent Dynamic Resistance	
HZ2.0 BP 1.88 2.12 40 200 0.5 25 40 HZ2.2 BP 2.08 2.33 40 200 0.7 20 40 CP 2.20 2.45 HZ2.4 BP 2.28 2.56 40 200 1.0 15 40 CP 2.40 2.70 HZ2.7 BP 2.5 2.9 40 200 1.0 15 40 CP 3.0 3.4 HZ3.0 BP 3.1 3.5 40 80 1.0 15 40 CP 3.3 3.7 HZ3.6 BP 3.4 3.8 40 60 1.0 15 40 CP 3.6 4.0 HZ3.9 BP 3.7 4.1 40 40 1.0 15 40 CP 3.9 4.4 HZ4.3 BP 4.0 4.5 40 CP 4.3 4.8 HZ4.4 BP 4.4 4.9 40 20 1.0 10 10 40			V _z (V)* ¹			I _R (μΑ)		r _d (Ω)	
CP 2.00 2.24 HZ2.2 BP 2.08 2.33 40 200 0.7 20 40 CP 2.20 2.45 40 200 1.0 15 40 CP 2.40 2.70 40 200 1.0 15 40 CP 2.40 2.9 40 200 1.0 15 40 CP 2.7 3.1 HZ3.0 BP 2.8 3.2 40 100 1.0 15 40 CP 3.0 3.4 40 80 1.0 15 40 CP 3.6 4.0 HZ3.9 BP 3.7 4.1 40 40 1.0 15 40 CP 3.9 4.4 HZ4.3 BP 4.0 4.5 40 20 1.0 15 40 CP 4.3 4.8 HZ4.7 BP 4.4	Type	Grade	Min	Max	I _z (mA)	Max	V _R (V)	Max	I _z (mA)
HZ2.2 BP 2.08 2.33 40 200 0.7 20 40 CP 2.20 2.45 40 200 1.0 15 40 HZ2.4 BP 2.28 2.56 40 200 1.0 15 40 CP 2.40 2.70 40 200 1.0 15 40 HZ3.7 BP 2.5 2.9 40 200 1.0 15 40 CP 2.7 3.1 3.1 3.2 40 100 1.0 15 40 CP 3.0 3.4 40 80 1.0 15 40 CP 3.3 3.7 40 80 1.0 15 40 HZ3.9 BP 3.7 4.1 40 40 1.0 15 40 CP 3.9 4.4 40 40 1.0 15 40 CP 4.3 4.8	HZ2.0	BP	1.88	2.12	40	200	0.5	25	40
CP 2.20 2.45 HZ2.4 BP 2.28 2.56 40 200 1.0 15 40 CP 2.40 2.70 40 200 1.0 15 40 HZ2.7 BP 2.5 2.9 40 200 1.0 15 40 CP 2.7 3.1 3.1 3.2 40 100 1.0 15 40 HZ3.3 BP 3.1 3.5 40 80 1.0 15 40 HZ3.6 BP 3.4 3.8 40 60 1.0 15 40 HZ3.9 BP 3.7 4.1 40 40 1.0 15 40 HZ4.3 BP 4.0 4.5 40 20 1.0 15 40 HZ4.7 BP 4.4 4.9 40 20 1.0 10 40		CP	2.00	2.24	_				
HZ2.4 BP 2.28 2.56 40 200 1.0 15 40 CP 2.40 2.70 40 200 1.0 15 40 HZ2.7 BP 2.5 2.9 40 200 1.0 15 40 CP 2.7 3.1 40 100 1.0 15 40 CP 3.0 3.4 40 80 1.0 15 40 HZ3.3 BP 3.1 3.5 40 80 1.0 15 40 HZ3.6 BP 3.4 3.8 40 60 1.0 15 40 HZ3.9 BP 3.7 4.1 40 40 1.0 15 40 HZ4.3 BP 4.0 4.5 40 20 1.0 15 40 HZ4.7 BP 4.4 4.9 40 20 1.0 10 40	HZ2.2	BP	2.08	2.33	40	200	0.7	20	40
CP 2.40 2.70 HZ2.7 BP 2.5 2.9 40 200 1.0 15 40 CP 2.7 3.1 40 100 1.0 15 40 CP 3.0 3.4 40 80 1.0 15 40 CP 3.3 3.7 40 80 1.0 15 40 HZ3.6 BP 3.4 3.8 40 60 1.0 15 40 HZ3.9 BP 3.7 4.1 40 40 1.0 15 40 HZ4.3 BP 4.0 4.5 40 20 1.0 15 40 CP 4.3 4.8 40 20 1.0 15 40 HZ4.7 BP 4.4 4.9 40 20 1.0 10 40		CP	2.20	2.45	_				
HZ2.7 BP 2.5 2.9 40 200 1.0 15 40 CP 2.7 3.1 40 100 1.0 15 40 HZ3.0 BP 2.8 3.2 40 100 1.0 15 40 CP 3.0 3.4 40 80 1.0 15 40 CP 3.3 3.7 40 60 1.0 15 40 HZ3.6 BP 3.4 3.8 40 60 1.0 15 40 HZ3.9 BP 3.7 4.1 40 40 1.0 15 40 HZ4.3 BP 4.0 4.5 40 20 1.0 15 40 HZ4.7 BP 4.4 4.9 40 20 1.0 10 40	HZ2.4	BP	2.28	2.56	40	200	1.0	15	40
CP 2.7 3.1 HZ3.0 BP 2.8 3.2 3.2 CP 3.0 3.4 40 100 1.0 15 40 HZ3.3 BP 3.1 3.5 SP 3.1 3.5 CP 3.3 3.7 40 80 1.0 15 40 HZ3.6 BP 3.4 3.8 SP 3.4 3.8 CP 3.6 4.0 40 60 1.0 15 40 HZ3.9 BP 3.7 4.1 SP 4.1		CP	2.40	2.70					
HZ3.0 BP 2.8 3.2 40 100 1.0 15 40 CP 3.0 3.4 40 80 1.0 15 40 HZ3.3 BP 3.1 3.5 40 80 1.0 15 40 CP 3.3 3.7 4.0 60 1.0 15 40 HZ3.9 BP 3.7 4.1 40 40 1.0 15 40 HZ4.3 BP 4.0 4.5 40 20 1.0 15 40 HZ4.7 BP 4.4 4.9 40 20 1.0 10 40	HZ2.7	BP	2.5	2.9	40	200	1.0	15	40
CP 3.0 3.4 HZ3.3 BP 3.1 3.5 40 80 1.0 15 40 CP 3.3 3.7 40 60 1.0 15 40 HZ3.6 BP 3.4 3.8 40 60 1.0 15 40 HZ3.9 BP 3.7 4.1 40 40 1.0 15 40 CP 3.9 4.4 40 20 1.0 15 40 HZ4.3 BP 4.0 4.5 40 20 1.0 15 40 HZ4.7 BP 4.4 4.9 40 20 1.0 10 40		СР	2.7	3.1					
HZ3.3 BP 3.1 3.5 40 80 1.0 15 40 CP 3.3 3.7 40 60 1.0 15 40 CP 3.6 4.0 40 40 1.0 15 40 HZ3.9 BP 3.7 4.1 40 40 1.0 15 40 CP 3.9 4.4 40 20 1.0 15 40 HZ4.3 BP 4.0 4.8 40 20 1.0 15 40 HZ4.7 BP 4.4 4.9 40 20 1.0 10 40	HZ3.0	BP	2.8	3.2	40	100	1.0	15	40
CP 3.3 3.7 HZ3.6 BP 3.4 3.8 40 60 1.0 15 40 CP 3.6 4.0 40 40 1.0 15 40 HZ3.9 BP 3.7 4.1 40 40 1.0 15 40 CP 3.9 4.4 HZ4.3 BP 4.0 4.5 40 20 1.0 15 40 CP 4.3 4.8 HZ4.7 BP 4.4 4.9 40 20 1.0 10 40		CP	3.0	3.4					
HZ3.6 BP 3.4 3.8 40 60 1.0 15 40 HZ3.9 BP 3.7 4.1 40 40 1.0 15 40 CP 3.9 4.4 40 20 1.0 15 40 HZ4.3 BP 4.0 4.5 40 20 1.0 15 40 HZ4.7 BP 4.4 4.9 40 20 1.0 10 40	HZ3.3	BP	3.1	3.5	40	80	1.0	15	40
CP 3.6 4.0 HZ3.9 BP 3.7 4.1 40 40 1.0 15 40 CP 3.9 4.4 HZ4.3 BP 4.0 4.5 40 20 1.0 15 40 CP 4.3 4.8 HZ4.7 BP 4.4 4.9 40 20 1.0 10 40		CP	3.3	3.7	_				
HZ3.9 BP 3.7 4.1 40 40 1.0 15 40 CP 3.9 4.4 40 20 1.0 15 40 HZ4.3 BP 4.0 4.5 40 20 1.0 15 40 HZ4.7 BP 4.4 4.9 40 20 1.0 10 40	HZ3.6	BP	3.4	3.8	40	60	1.0	15	40
CP 3.9 4.4 HZ4.3 BP 4.0 4.5 40 20 1.0 15 40 CP 4.3 4.8 HZ4.7 BP 4.4 4.9 40 20 1.0 10 40		СР	3.6	4.0	_				
HZ4.3 BP 4.0 4.5 40 20 1.0 15 40 CP 4.3 4.8 HZ4.7 BP 4.4 4.9 40 20 1.0 10 40	HZ3.9	BP	3.7	4.1	40	40	1.0	15	40
CP 4.3 4.8 HZ4.7 BP 4.4 4.9 40 20 1.0 10 40		CP	3.9	4.4					
HZ4.7 BP 4.4 4.9 40 20 1.0 10 40	HZ4.3	BP	4.0	4.5	40	20	1.0	15	40
		СР	4.3	4.8	_				
CP 4.7 5.2	HZ4.7	BP	4.4	4.9	40	20	1.0	10	40
		СР	4.7	5.2	-				

Note: 1. Tested with DC.

Electrical Characteristics (cont)

 $(Ta = 25^{\circ}C)$

		Zener Voltage			Reverse Current		Dynamic Resistance	
		V _z (V)* ¹		Test Condition	I _R (μ A)	Test Condition	r _d (Ω)	Test Condition
Type	Grade	Min	Max	I _z (mA)	Max	V _R (V)	Max	I _z (mA)
HZ5.1	BP	4.8	5.4	40	20	1.0	8	40
	СР	5.1	5.7					
HZ5.6	BP	5.3	6.0	40	20	1.5	8	40
	СР	5.6	6.3					
HZ6.2	BP	5.8	6.6	40	20	3.0	6	40
	СР	6.2	7.0					
HZ6.8	BP	6.4	7.2	40	20	3.5	6	40
	СР	6.8	7.7					
HZ7.5	BP	7.0	7.9	40	20	4.0	4	40
	СР	7.5	8.4					
HZ8.2	BP	7.7	8.7	40	20	5.0	4	40
	CP	8.2	9.3	_				
HZ9.1	BP	8.5	9.6	40	20	6.0	6	40
	СР	9.1	10.2					
HZ10	BP	9.4	10.6	40	10	7.0	6	40
	СР	10.0	11.2					
HZ11	BP	10.4	11.6	20	10	8.0	8	20
	СР	11.0	12.3					
HZ12	BP	11.4	12.6	20	10	9.0	8	20
	СР	12.0	13.5					
HZ13	BP	12.4	14.1	20	10	10.0	10	20
	СР	13.3	15.0					
HZ15	BP	13.8	15.6	20	10	11.0	10	20
	СР	14.7	16.5					
HZ16	BP	15.3	17.1	20	10	12.0	12	20
	СР	16.2	18.3					
HZ18	BP	16.8	19.1	20	10	13.0	12	20
	СР	18.0	20.3	<u> </u>				
HZ20	BP	18.8	21.2	20	10	15.0	14	20
	СР	20.0	22.4					

Note: 1. Tested with DC.

Electrical Characteristics (cont)

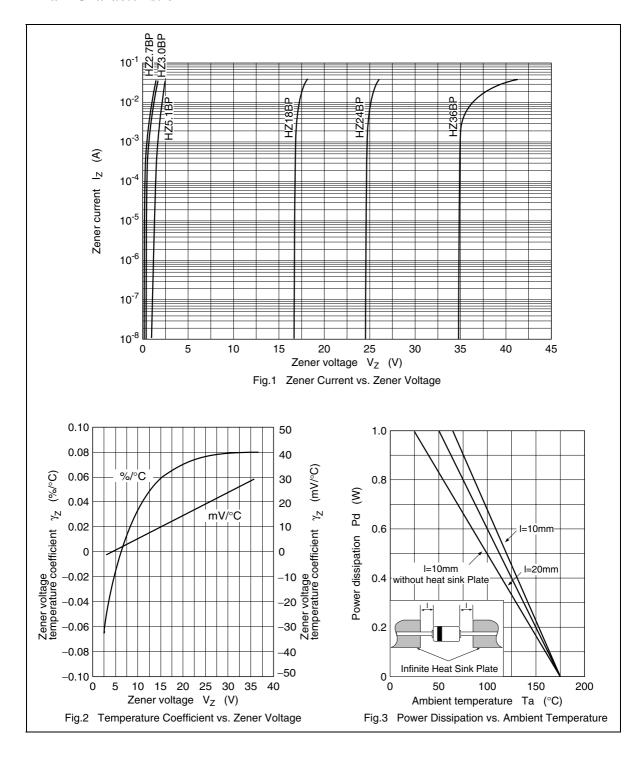
 $(Ta = 25^{\circ}C)$

		Zener Voltage			Reverse Current		Dynamic Resistance	
		V _z (V)* ¹		Test Condition	I _R (μΑ)	Test Condition	r _d (Ω)	Test Condition
Type	Grade	Min	Max	I _z (mA)	Max	V _R (V)	Max	I _z (mA)
HZ22	BP	20.8	23.3	10	10	17.0	14	10
	СР	22.0	24.5					
HZ24	BP	22.8	25.6	10	10	19.0	16	10
	СР	24.0	27.6					
HZ27	BP	25.1	28.9	10	10	21.0	16	10
	СР	27.0	30.8					
HZ30	BP	28.0	32.0	10	10	23.0	18	10
	СР	30.0	34.0					
HZ33	BP	31.0	35.0	10	10	25.0	18	10
	СР	33.0	37.0					
HZ36	BP	34.0	38.0	10	10	27.0	20	10
	СР	36.0	40.0				_	

Notes: 1. Tested with DC.

^{2.} Type No. is as follows; HZ2.0BP, HZ2.0CP, • • • HZ36BP, HZ36CP.

Main Characteristic



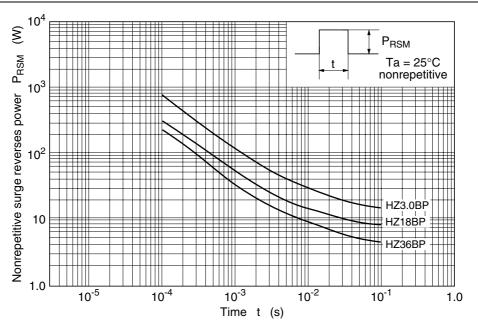
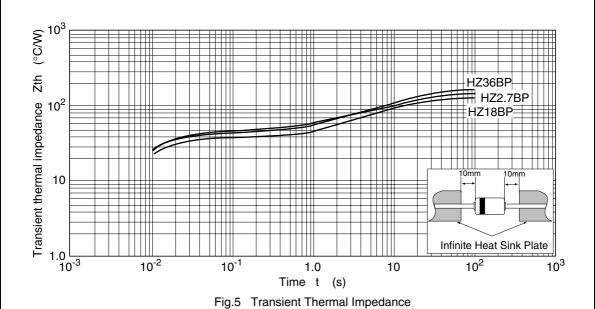
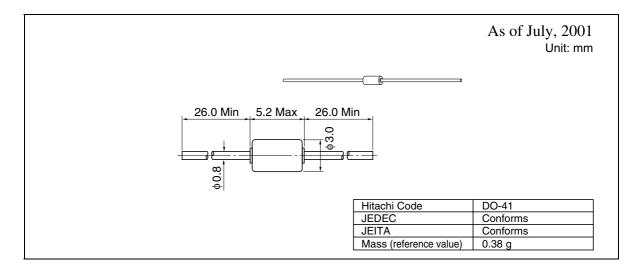


Fig.4 Surge Reverse Power Ratings (Reference Data)



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Package Dimensions



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